

SBAS043C – MARCH 1997 – REVISED SEPTEMBER 2005

Low-Power, Serial 16-Bit Sampling ANALOG-TO-DIGITAL CONVERTER

FEATURES

- 20 μ s max CONVERSION TIME
- SINGLE +5V SUPPLY OPERATION
- PIN-COMPATIBLE WITH 12-BIT ADS7812
- EASY-TO-USE SERIAL INTERFACE
- 0.3" DIP-16 AND SO-16
- ± 2.0 LSB max INL
- 87dB min SINAD
- USES INTERNAL OR EXTERNAL REFERENCE
- MULTIPLE INPUT RANGES
- 35mW max POWER DISSIPATION
- NO MISSING CODES
- 50 μ W POWER DOWN MODE

DESCRIPTION

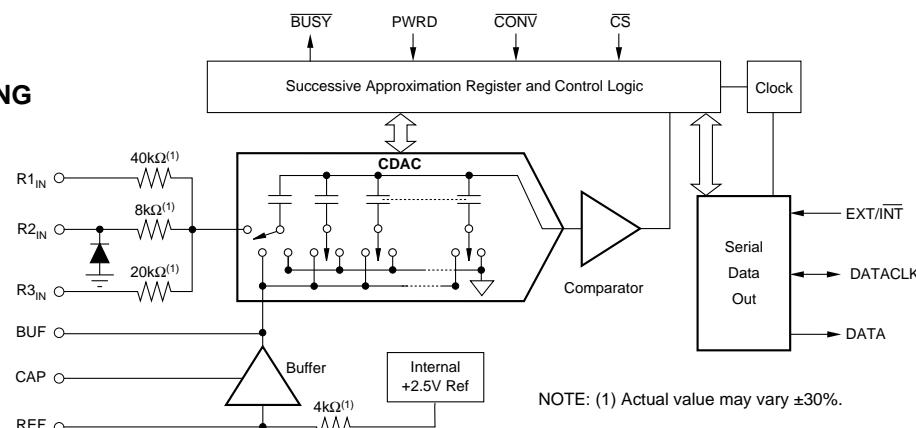
The ADS7813 is a low-power, single +5V supply, 16-bit sampling analog-to-digital (A/D) converter. It contains a complete 16-bit capacitor-based SAR A/D with a sample/hold, clock, reference, and serial data interface.

The converter can be configured for a variety of input ranges including ± 10 V, ± 5 V, 0V to 10V, and 0.5V to 4.5V. A high impedance 0.3V to 2.8V input range is also available (input impedance $> 10M\Omega$). For most input ranges, the input voltage can swing to +16.5V or -16.5V without damage to the converter.

A flexible SPI-compatible serial interface allows data to be synchronized to an internal or external clock. The ADS7813 is specified at a 40kHz sampling rate over the -40°C to +85°C temperature range. It is available in a 0.3" DIP-16 or an SO-16 package.

APPLICATIONS

- MEDICAL INSTRUMENTATION
- DATA ACQUISITION SYSTEMS
- ROBOTICS
- INDUSTRIAL CONTROL
- TEST EQUIPMENT
- DIGITAL SIGNAL PROCESSING
- DSP SERVO CONTROL



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Analog Inputs: R1 _{IN}	±16.5V
R2 _{IN}	GND – 0.3V to +16.5V
R3 _{IN}	±16.5V
REF	GND – 0.3V to V _S + 0.3V
CAP	Indefinite Short to GND Momentary Short to V _S
V _S	7V
Digital Inputs	GND – 0.3V to V _S + 0.3V
Maximum Junction Temperature	+165°C
Internal Power Dissipation	825mW
Lead Temperature (soldering, 10s)	+300°C

NOTE: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability.

ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION⁽¹⁾

PRODUCT	MAXIMUM INTEGRAL LINEARITY ERROR (LSB)	SPECIFIED NO MISSING CODE LEVEL (LSB)	MINIMUM SIGNAL-TO-(NOISE + DISTORTION) RATIO (DB)	PACKAGE-LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
ADS7813P	±3	15	85	Dip-16	N	-40°C to +85°C	ADS7813P	ADS7813P	Tubes, 25
ADS7813PB	±2	16	87	"	"	"	ADS7813PB	ADS7813PB	Tubes, 25
ADS7813U	±3	15	85	SO-16	DW	-40°C to +85°C	ADS7813U	ADS7813U	Tubes, 48
"	"	"	"	"	"	"	"	ADS7813U/1K	Tape and Reel, 1000
ADS7813UB	±2	16	87	SO-16	DW	-40°C to +85°C	ADS7813UB	ADS7813UB	Tubes, 48
"	"	"	"	"	"	"	"	ADS7813UB/1K	Tape and Reel, 1000

NOTE: (1) For the most current package and ordering information, see the Package Option Addendum at the end of this data sheet, or see the TI web site at www.ti.com.

ELECTRICAL CHARACTERISTICS

At T_A = -40°C to +85°C, f_S = 40kHz, V_S = +5V ±5%, using internal reference, unless otherwise specified.

PARAMETER	CONDITIONS	ADS7813P, U			ADS7813PB, UB			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
RESOLUTION				16			*	Bits
ANALOG INPUT								
Voltage Range		See Table I				*		
Impedance		See Table I				*		
Capacitance		35				*		pF
THROUGHPUT SPEED								
Conversion Time							*	μs
Complete Cycle	Acquire and Convert			20			*	μs
Throughput Rate		40		25			*	kHz
DC ACCURACY								
Integral Linearity Error							*	LSB ⁽¹⁾
Differential Linearity Error							*	LSB
No Missing Codes								Bits
Transition Noise ⁽²⁾								LSB
Full Scale Error ⁽³⁾								%
Full Scale Error Drift								ppm/°C
Full Scale Error ⁽³⁾								%
Full Scale Error Drift								ppm/°C
Bipolar Zero Error								mV
Bipolar Zero Error Drift								ppm/°C
Unipolar Zero Error								mV
Unipolar Zero Error Drift								ppm/°C
Recovery Time to Rated Accuracy from Power Down ⁽⁴⁾	1.0μF Capacitor to CAP							μs
Power Supply Sensitivity	+4.75V < (V _S = +5V) < +5.25							LSB
AC ACCURACY								
Spurious-Free Dynamic Range	f _{IN} = 1kHz	90	100		96	102		dB ⁽⁵⁾
Total Harmonic Distortion	f _{IN} = 1kHz		–98	–90		–100		dB
Signal-to-(Noise+Distortion)	f _{IN} = 1kHz	85	89		87	*		dB
Signal-to-Noise	f _{IN} = 1kHz	85	89		87	*		dB
Useable Bandwidth ⁽⁶⁾								kHz
Full Power –3dB Bandwidth								kHz

ELECTRICAL CHARACTERISTICS (Cont.)

At $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $f_S = 40\text{kHz}$, $V_S = +5V \pm 5\%$, using internal reference, unless otherwise specified.

PARAMETER	CONDITIONS	ADS7813P, U			ADS7813PB, UB			UNITS
		MIN	TYP	MAX	MIN	TYP	MAX	
SAMPLING DYNAMICS								
Aperture Delay			40			*		ns
Aperture Jitter			20			*		ps
Transient Response			5			*		μs
Overvoltage Recovery ⁽⁷⁾			750			*		ns
REFERENCE								
Internal Reference Voltage		2.48	2.5	2.52	*	*	*	V
Internal Reference Source Current			100			*		μA
Internal Reference Drift			8			*		$\text{ppm}/^\circ\text{C}$
External Reference Voltage Range		2.3	2.5	2.7	*	*	*	V
External Reference Current Drain				100		*		μA
CAP Compensation Capacitors ESR ⁽⁸⁾				3		*		Ω
DIGITAL INPUTS								
Logic Levels								
V_{IL}			-0.3			*		V
$V_{IH}^{(9)}$			+2.0			*		V
I_{IL}						*		μA
I_{IH}						*		μA
DIGITAL OUTPUTS								
Data Format								
Data Coding								
V_{OL}								V
V_{OH}								V
Leakage Current								μA
Output Capacitance								pF
POWER SUPPLY								
V_S								V
Power Dissipation								mW
TEMPERATURE RANGE								
Specified Performance								$^\circ\text{C}$
Derated Performance								$^\circ\text{C}$

* Same specification as grade to the left.

NOTES: (1) LSB means Least Significant Bit. For the $\pm 10\text{V}$ input range, one LSB is $305\mu\text{V}$.

(2) Typical rms noise at worst case transitions and temperatures.

(3) Full scale error is the worst case of -Full Scale or +Full Scale untrimmed deviation from ideal first and last code transitions, divided by the transition voltage (not divided by the full-scale range) and includes the effect of offset error.

(4) After the ADS7813 is initially powered on and fully settles, this is the time delay after it is brought out of Power Down Mode until all internal settling occurs and the analog input is acquired to rated accuracy, and normal conversions can begin again.

(5) All specifications in dB are referred to a full-scale input.

(6) Useable Bandwidth defined as Full-Scale input frequency at which Signal-to-(Noise+Distortion) degrades to 60dB, or 10 bits of accuracy.

(7) Recovers to specified performance after $2 \times \text{FS}$ input overvoltage.

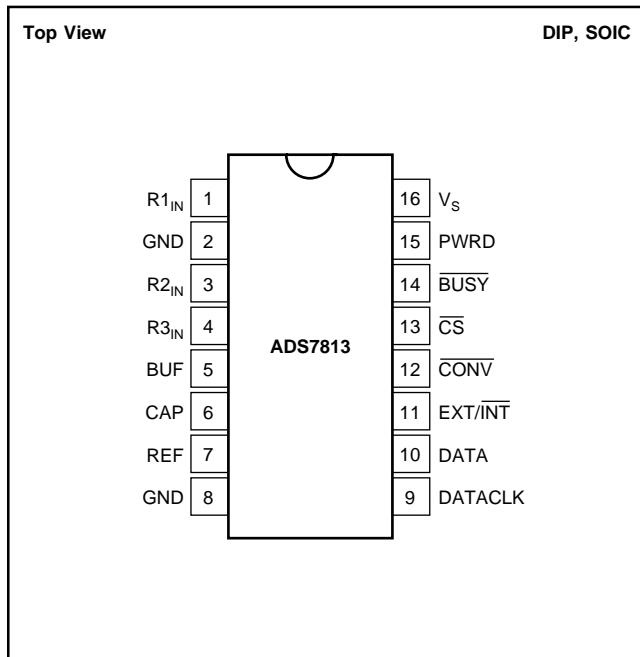
(8) ESR = total equivalent series resistance for the compensation capacitors.

(9) The minimum V_{IH} level for the DATACLK signal is 3V.

PIN CONFIGURATION

PIN #	NAME	DESCRIPTION
1	R1 _{IN}	Analog Input. See Tables I and IV.
2	GND	Ground
3	R2 _{IN}	Analog Input. See Tables I and IV.
4	R3 _{IN}	Analog Input. See Tables I and IV.
5	BUF	Reference Buffer Output. Connect to R1 _{IN} , R2 _{IN} , or R3 _{IN} , as needed.
6	CAP	Reference Buffer Compensation Node. Decouple to ground with a 1 μ F tantalum capacitor in parallel with a 0.01 μ F ceramic capacitor.
7	REF	Reference Input/Output. Outputs internal +2.5V reference via a series 4k Ω resistor. Decouple this voltage with a 1 μ F to 2.2 μ F tantalum capacitor to ground. If an external reference voltage is applied to this pin, it will override the internal reference.
8	GND	Ground
9	DATACLK	Data Clock Pin. With EXT/INT LOW, this pin is an output and provides the synchronous clock for the serial data. The output is tri-stated when CS is HIGH. With EXT/INT HIGH, this pin is an input and the serial data clock must be provided externally.
10	DATA	Serial Data Output. The serial data is always the result of the last completed conversion and is synchronized to DATACLK. If DATACLK is from the internal clock (EXT/INT LOW), the serial data is valid on both the rising and falling edges of DATACLK. DATA is tri-stated when CS is HIGH.
11	EXT/INT	External or Internal DATACLK Pin. Selects the source of the synchronous clock for serial data. If HIGH, the clock must be provided externally. If LOW, the clock is derived from the internal conversion clock. Note that the clock used to time the conversion is always internal regardless of the status of EXT/INT.
12	CONV	Convert Input. A falling edge on this input puts the internal sample/hold into the hold state and starts a conversion regardless of the state of CS. If a conversion is already in progress, the falling edge is ignored. If EXT/INT is LOW, data from the previous conversion will be serially transmitted during the current conversion.
13	CS	Chip Select. This input tri-states all outputs when HIGH and enables all outputs when LOW. This includes DATA, BUSY, and DATACLK (when EXT/INT is LOW). Note that a falling edge on CONV will initiate a conversion even when CS is HIGH.
14	BUSY	Busy Output. When a conversion is started, BUSY goes LOW and remains LOW throughout the conversion. If EXT/INT is LOW, data is serially transmitted while BUSY is LOW. BUSY is tri-stated when CS is HIGH.
15	PWRD	Power Down Input. When HIGH, the majority of the ADS7813 is placed in a low power mode and power consumption is significantly reduced. CONV must be taken LOW prior to PWRD going LOW in order to achieve the lowest power consumption. The time required for the ADS7813 to return to normal operation after power down depends on a number of factors. Consult the Power Down section for more information.
16	V _S	+5V Supply Input. For best performance, decouple to ground with a 0.1 μ F ceramic capacitor in parallel with a 10 μ F tantalum capacitor.

PIN CONFIGURATION

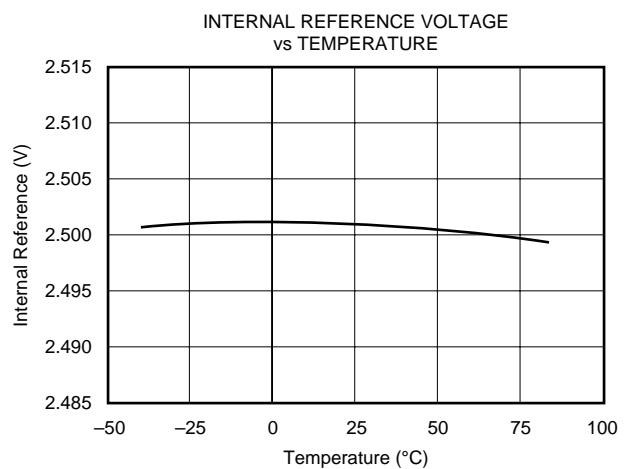
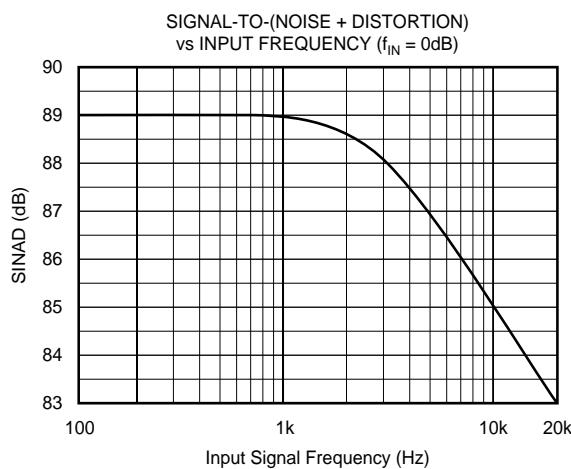
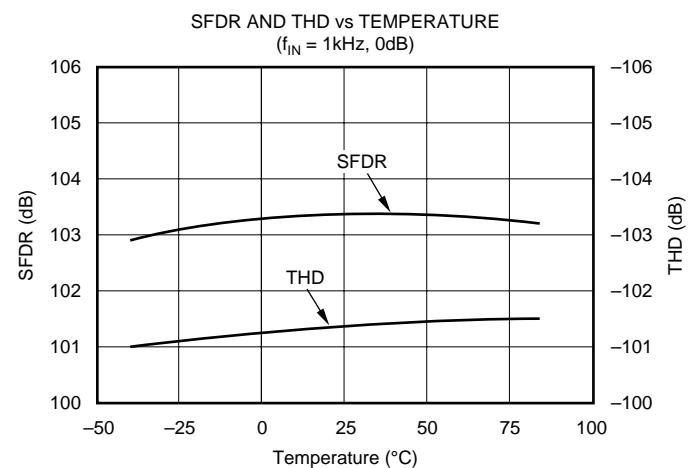
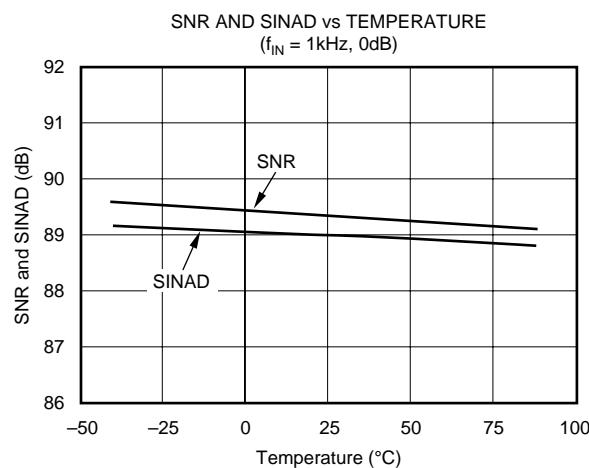
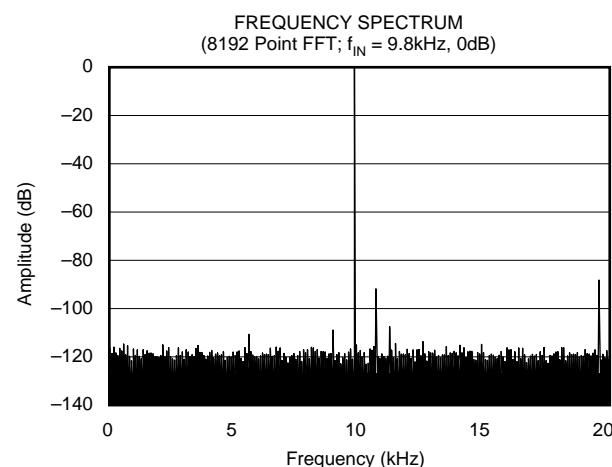
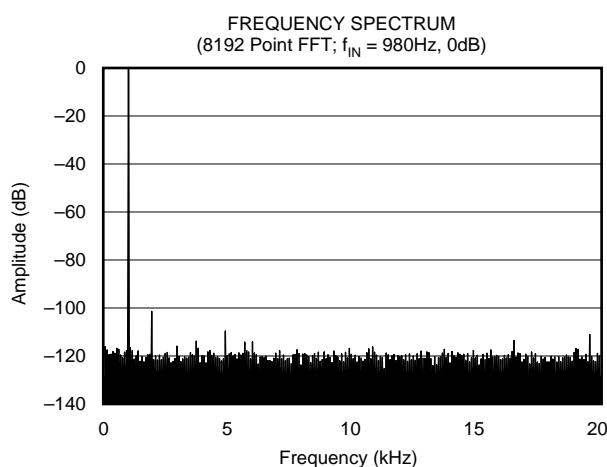


ANALOG INPUT RANGE (V)	CONNECT R1 _{IN} TO	CONNECT R2 _{IN} TO	CONNECT R3 _{IN} TO	INPUT IMPEDANCE (k Ω)
$\pm 10V$	V _{IN}	BUF	GND	45.7
0.3125V to 2.8125V	V _{IN}	V _{IN}	V _{IN}	> 10,000
$\pm 5V$	GND	BUF	V _{IN}	26.7
0V to 10V	BUF	GND	V _{IN}	26.7
0V to 4V	BUF	V _{IN}	GND	21.3
$\pm 3.33V$	V _{IN}	BUF	V _{IN}	21.3
0.5V to 4.5V	GND	V _{IN}	GND	21.3

TABLE I. ADS7813 Input Ranges.

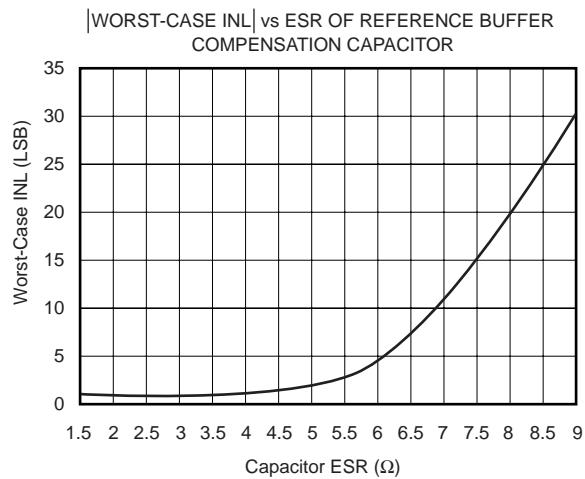
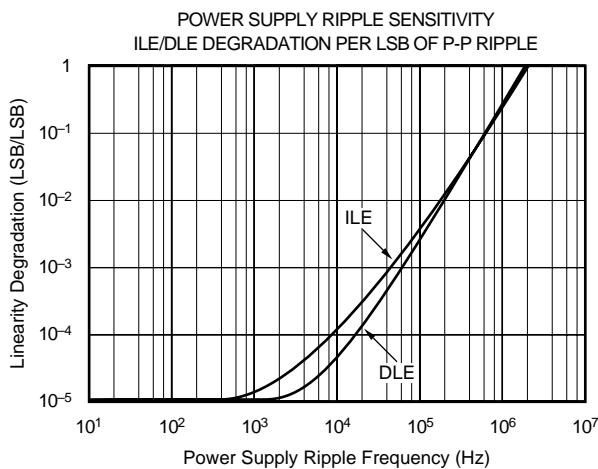
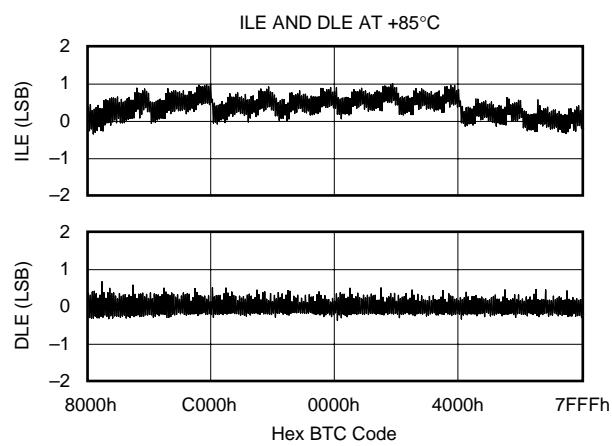
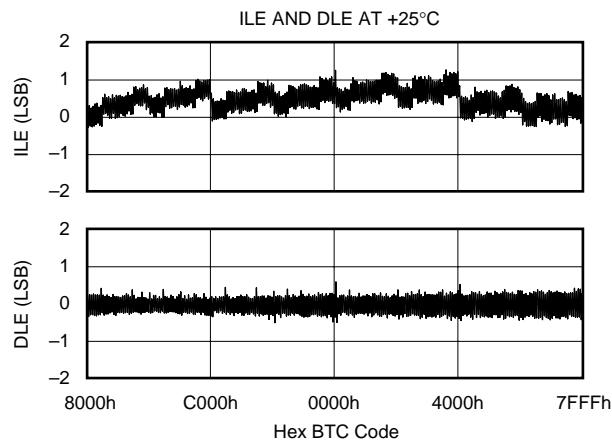
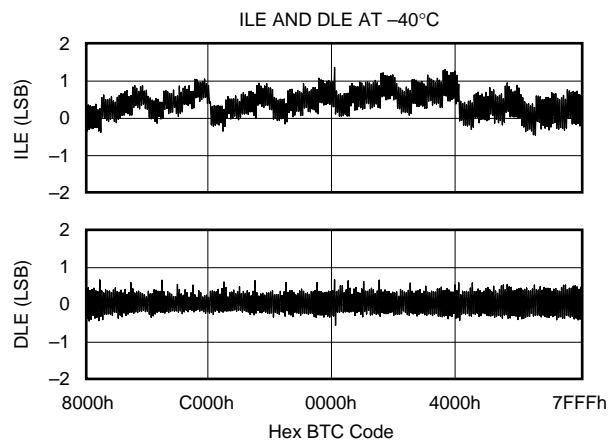
TYPICAL PERFORMANCE CURVES

At $T_A = +25^\circ\text{C}$, $f_S = 40\text{kHz}$, $V_S = +5\text{V}$, $\pm 10\text{V}$ input range, using internal reference, unless otherwise noted.



TYPICAL PERFORMANCE CURVES (Cont.)

At $T_A = +25^\circ\text{C}$, $f_S = 40\text{kHz}$, $V_S = +5\text{V}$, $\pm 10\text{V}$ input range, using internal reference, unless otherwise noted.



BASIC OPERATION

INTERNAL DATACLK

Figure 1a shows a basic circuit to operate the ADS7813 with a $\pm 10V$ input range. To begin a conversion and serial transmission of the results from the previous conversion, a falling edge must be provided to the CONV input. BUSY will go LOW indicating that a conversion has started and will stay LOW until the conversion is complete. During the conversion, the results of the previous conversion will be transmitted via DATA while DATACLK provides the synchronous clock for the serial data. The data format is 16-bit, Binary Two's Complement, and MSB first. Each data bit is valid on both the rising and falling edge of DATACLK. BUSY is LOW during the entire serial transmission and can be used as a frame synchronization signal.

EXTERNAL DATACLK

Figure 1b shows a basic circuit to operate the ADS7813 with a $\pm 10V$ input range. To begin a conversion, a falling edge must be provided to the CONV input. BUSY will go LOW indicating that a conversion has started and will stay LOW until the conversion is complete. Just prior to BUSY rising near the end of the conversion, the internal working register holding the conversion result will be transferred to the internal shift register.

The internal shift register is clocked via the DATACLK input. The recommended method of reading the conversion result is to provide the serial clock after the conversion has completed. See External DATACLK under the Reading Data section of this data sheet for more information.

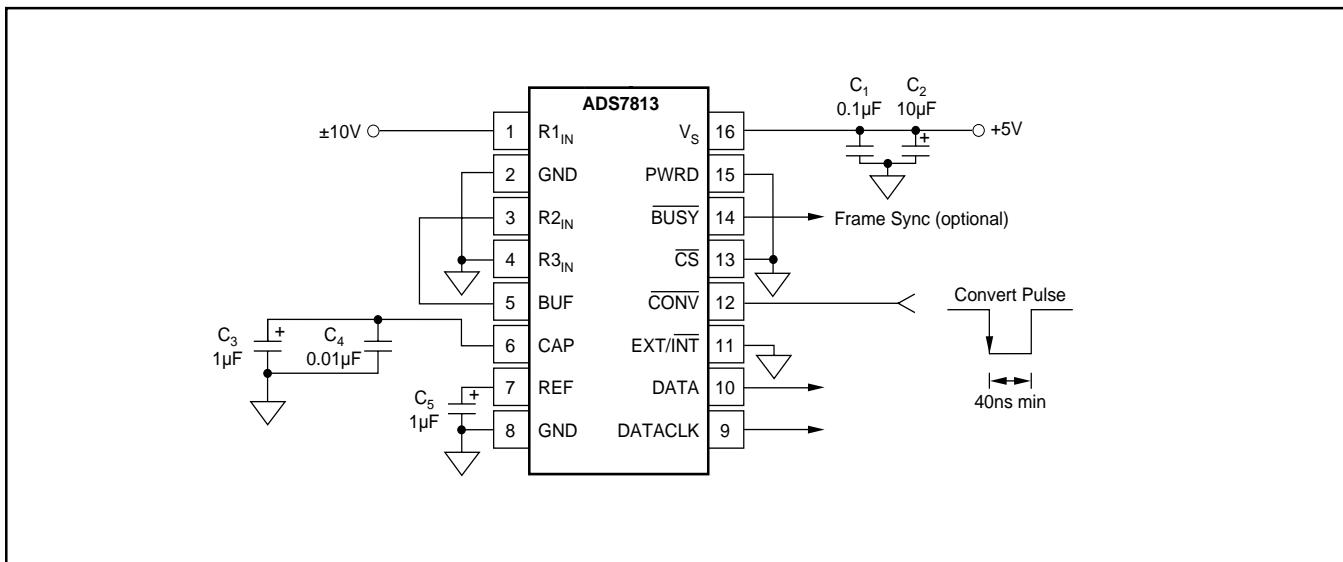


FIGURE 1a. Basic Operation, $\pm 10V$ Input Range, Internal DATACLK.

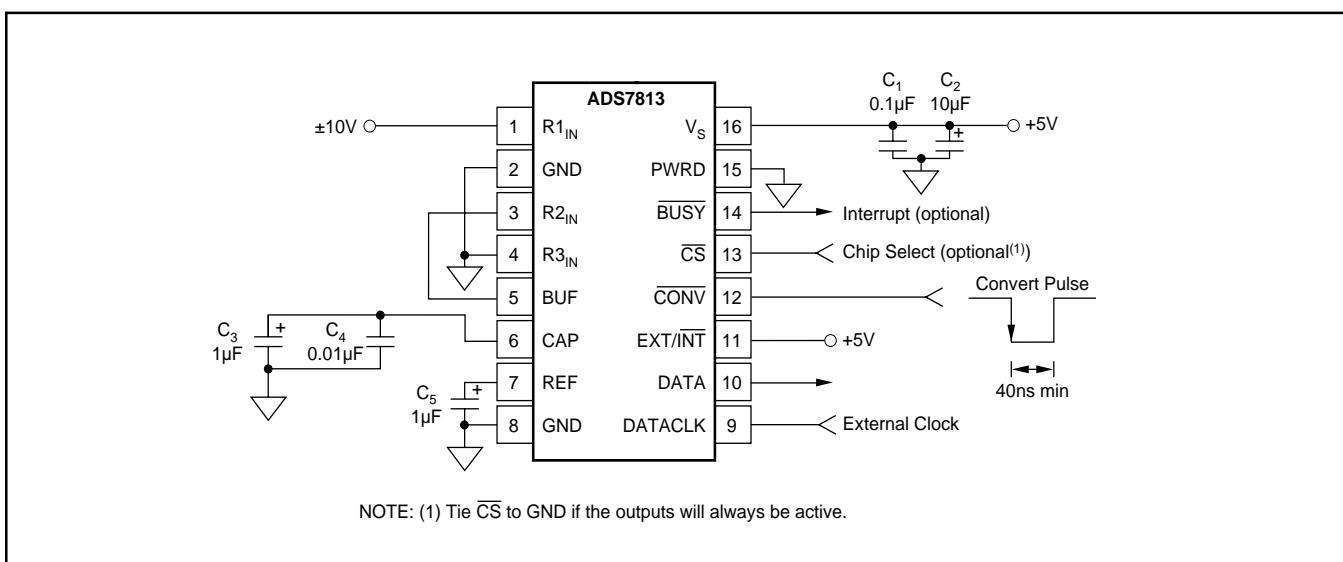


FIGURE 1b. Basic Operation, $\pm 10V$ Input Range, External DATACLK.

SYMBOL	DESCRIPTION	MIN	TYP	MAX	UNITS
t_1	Conversion Plus Acquisition Time			25	μs
t_2	CONV LOW to All Digital Inputs Stable			8	μs
t_3	CONV LOW to Initiate a Conversion	40			ns
t_4	BUSY Rising to Any Digital Input Active	0			ns
t_5	CONV HIGH Prior to Start of Conversion	2			μs
t_6	BUSY LOW	19	20		μs
t_7	CONV LOW to BUSY LOW	85	120		ns
t_8	Aperture Delay	40			ns
t_9	Conversion Time	18	20		μs
t_{10}	Conversion Complete to BUSY Rising	1.1	2		μs
t_{11}	Acquisition Time			5	μs
t_{12}	CONV LOW to Rising Edge of First DATACLK		1.4		μs
t_{13}	Internal DATACLK HIGH	250	350	500	ns
t_{14}	Internal DATACLK LOW	600	760	875	ns
t_{15}	Internal DATACLK Period			1.1	μs
t_{16}	DATA Valid to Internal DATACLK Rising	20			ns
t_{17}	Internal DATACLK Falling to DATA Not Valid	400			ns
t_{18}	Falling Edge of Last DATACLK to BUSY Rising		800		ns
t_{19}	External DATACLK Rising to DATA Not Valid	15			ns
t_{20}	External DATACLK Rising to DATA Valid		55	85	ns
t_{21}	External DATACLK HIGH	50			ns
t_{22}	External DATACLK LOW	50			ns
t_{23}	External DATACLK Period	100			ns
t_{24}	CONV LOW to External DATACLK Active	100			ns
t_{25}	External DATACLK LOW or CS HIGH to BUSY Rising	2			μs
t_{26}	CS LOW to Digital Outputs Enabled	85			ns
t_{27}	CS HIGH to Digital Outputs Disabled	85			ns

TABLE II. ADS7813 Timing. $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$.

STARTING A CONVERSION

If a CONV is not currently in progress, a falling edge on the CONV input places the sample and hold into the hold mode and begins a conversion, as shown in Figure 2 and with the timing given in Table II. During the conversion, the CONV input is ignored. Starting a conversion does not depend on the state of CS. A conversion can be started once every 25μs (40kHz maximum conversion rate). There is no minimum conversion rate.

Even though the CONV input is ignored while a conversion is in progress, this input should be held static during the conversion period. Transitions on this digital input can easily couple into sensitive analog portions of the converter, adversely affecting the conversion results (see the Sensitivity to External Digital Signals section of this data sheet for more information).

Ideally, the CONV input should go LOW and remain LOW throughout the conversion. It should return HIGH sometime after BUSY goes HIGH. In addition, it should be HIGH prior to the start of the next conversion for a minimum time period given by t_5 . This will ensure that the digital transition on the CONV input will not affect the signal that is acquired for the next conversion.

An acceptable alternative is to return the CONV input HIGH as soon after the start of the conversion as possible. For example, a negative going pulse 100ns wide would make a good CONV input signal. It is strongly recommended that from time t_2 after the start of a conversion until BUSY rises, the CONV input should be held static (either HIGH or LOW). During this time, the converter is more sensitive to external noise.

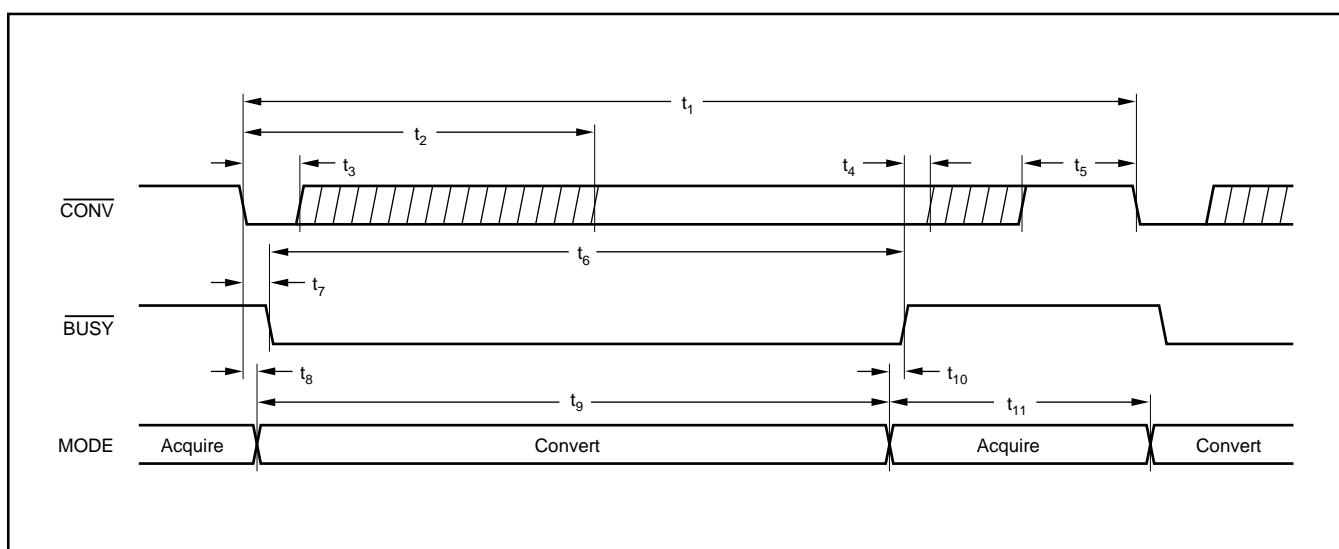


FIGURE 2. Basic Conversion Timing.

DESCRIPTION	ANALOG INPUT		DIGITAL OUTPUT	
Full-Scale Range Least Significant Bit (LSB)	$\pm 10V$ $305\mu V$	0.5V to 4.5V $61\mu V$	BINARY TWO'S COMPLEMENT	
			BINARY CODE	HEX CODE
+Full Scale -1LSB	9.999695V	4.499939V	0111 1111 1111 1111	7FFF
Midscale	0V	2.5V	0000 0000 0000 0000	0000
Midscale -1LSB	-305 μV	2.499939 μV	1111 1111 1111 1111	FFFF
-Full Scale	-10V	0.5V	10000 0000 0000 0000	8000

TABLE III. Ideal Input Voltage and Corresponding Digital Output for Two Common Input Ranges.

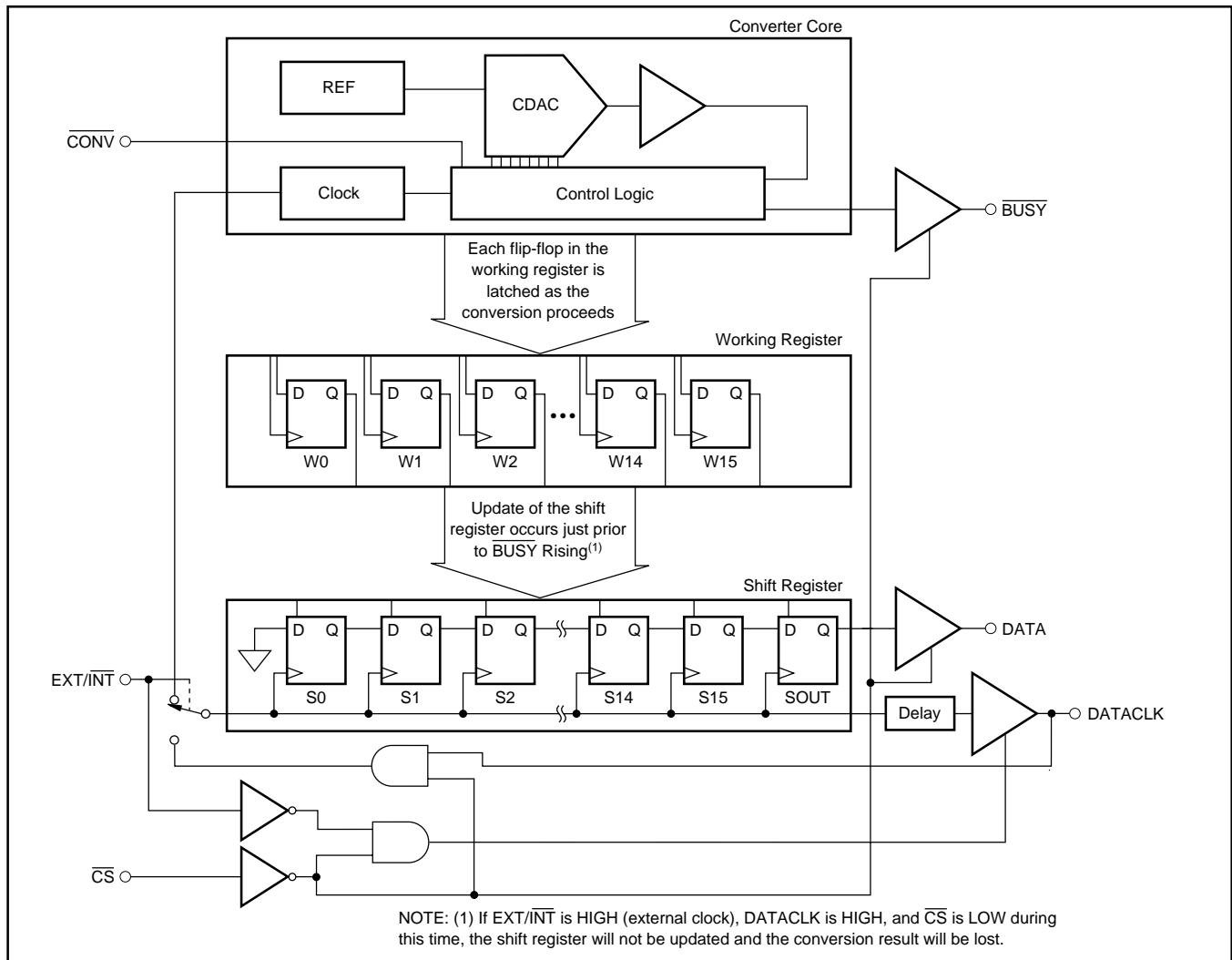


FIGURE 3. Block Diagram of the ADS7813's Digital Inputs and Outputs.

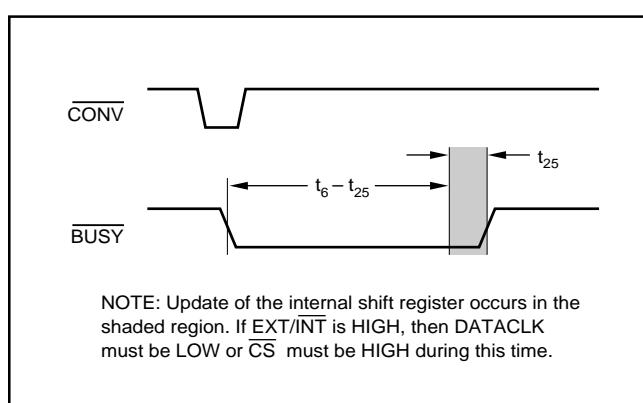


FIGURE 4. Timing of the Shift Register Update.

READING DATA

The ADS7813 digital output is in Binary Two's Complement (BTC) format. Table III shows the relationship between the digital output word and the analog input voltage under ideal conditions.

Figure 3 shows the relationship between the various digital inputs, digital outputs, and internal logic of the ADS7813. Figure 4 shows when the internal shift register of the ADS7813 is updated and how this relates to a single conversion cycle. Together, these two figures point out a very important aspect of the ADS7813: the conversion result is not available until after the conversion is complete. The implications of this are discussed in the following sections.

INTERNAL DATACLK

With $\text{EXT/INT}^{\overline{}} \text{ tied LOW}$, the result from conversion 'n' is serially transmitted during conversion 'n+1', as shown in Figure 5 and with the timing given in Table II. Serial transmission of data occurs only during a conversion. When a transmission is not in progress, DATA and DATACLK are LOW.

During the conversion, the results of the previous conversion will be transmitted via DATA, while DATACLK provides the synchronous clock for the serial data. The data format is 16-bit, Binary Two's Complement, and MSB first. Each data bit is valid on both the rising and falling edges of DATACLK. BUSY is LOW during the entire serial transmission and can be used as a frame synchronization signal.

EXTERNAL DATACLK

With $\text{EXT/INT}^{\overline{}} \text{ tied HIGH}$, the result from conversion 'n' is clocked out after the conversion has completed, during the next conversion ('n+1'), or a combination of these two. Figure 6 shows the case of reading the conversion result after the conversion is complete. Figure 7 describes reading the result during the next conversion. Figure 8 combines the important aspects of Figures 6 and 7 as to reading part of the result after the conversion is complete and the remainder during the next conversion.

The serial transmission of the conversion result is initiated by a rising edge on DATACLK. The data format is 16-bit, Binary Two's Complement, and MSB first. Each data bit is valid on the falling edge of DATACLK. In some cases, it

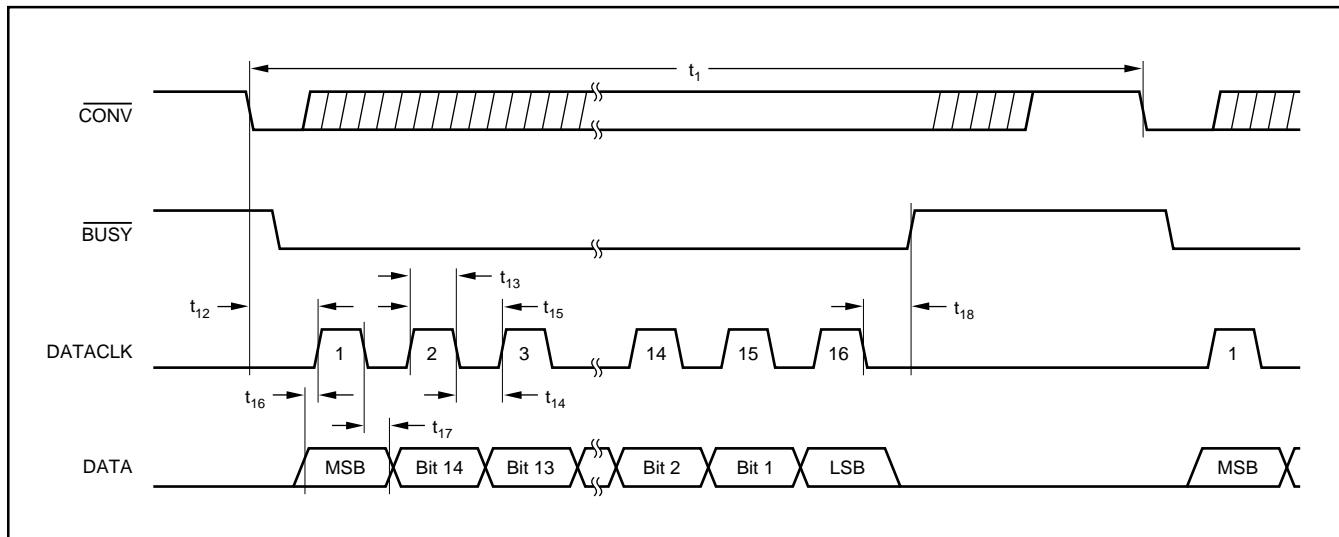


FIGURE 5. Serial Data Timing, Internal Clock (EXT/INT and CS LOW).

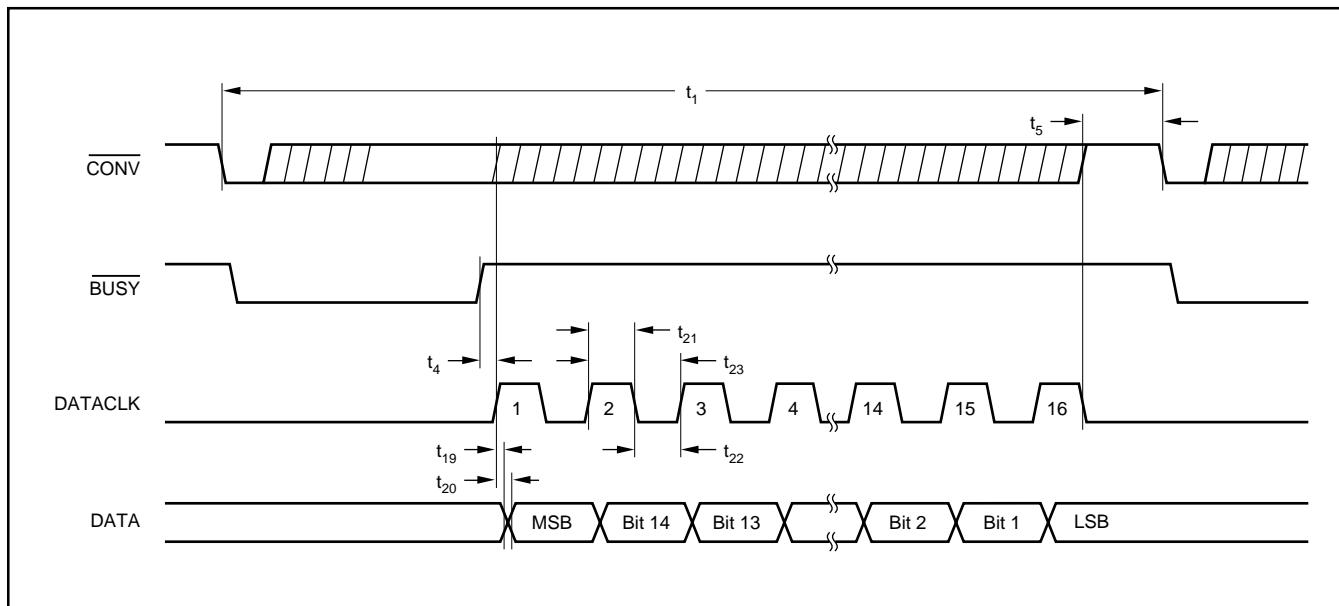


FIGURE 6. Serial Data Timing, External Clock, Clocking After the Conversion Completes (EXT/INT HIGH, CS LOW).

might be possible to use the rising edge of the DATACLK signal. However, one extra clock period (not shown in Figures 6, 7, and 8) is needed for the final bit.

The external DATACLK signal must be LOW or \overline{CS} must be HIGH prior to \overline{BUSY} rising (see time t_{25} in Figures 7 and 8). If this is not observed during this time, the output shift register of the ADS7813 will not be updated with the conversion result. Instead, the previous contents of the shift register will remain and the new result will be lost.

Before reading the next three paragraphs, consult the Sensitivity to External Digital Signals section of this data sheet. This will explain many of the concerns regarding how and when to apply the external DATACLK signal.

External DATACLK Active After the Conversion

The preferred method of obtaining the conversion result is to provide the DATACLK signal after the conversion has been

completed and before the next conversion starts—as shown in Figure 6. Note that the DATACLK signal should be static before the start of the next conversion. If this is not observed, the DATACLK signal could affect the voltage that is acquired.

External DATACLK Active During the Next Conversion

Another method of obtaining the conversion result is shown in Figure 7. Since the output shift register is not updated until the end of the conversion, the previous result remains valid during the next conversion. If a fast clock ($\geq 2\text{MHz}$) can be provided to the ADS7813, the result can be read during time t_2 . During this time, the noise from the DATACLK signal is less likely to affect the conversion result.

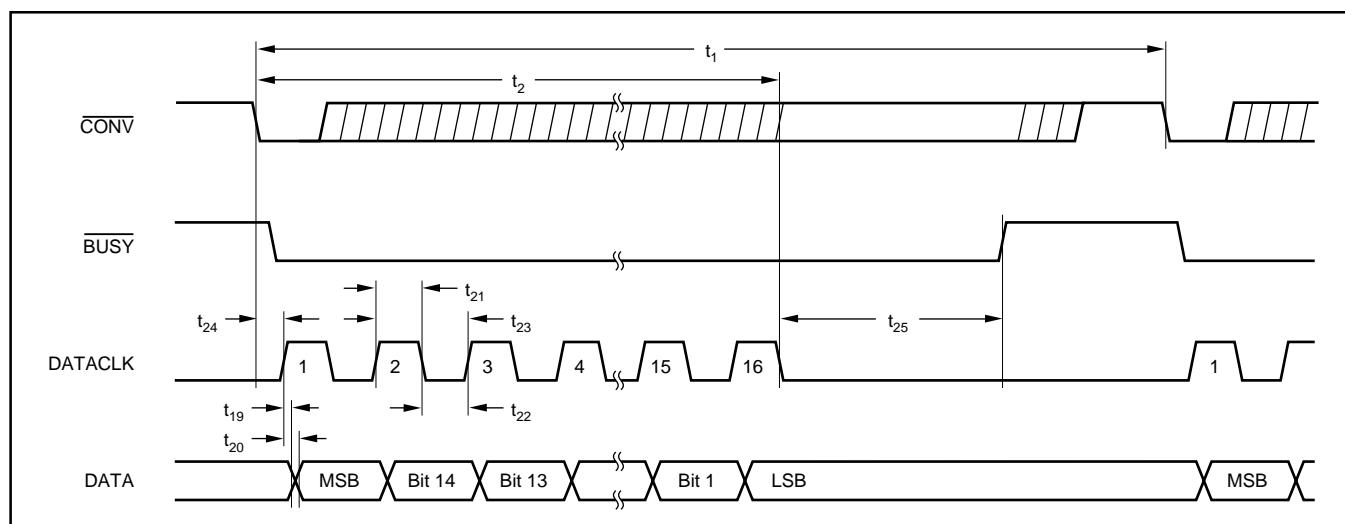


FIGURE 7. Serial Data Timing, External Clock, Clocking During the Next Conversion (EXT/INT HIGH, \overline{CS} LOW).

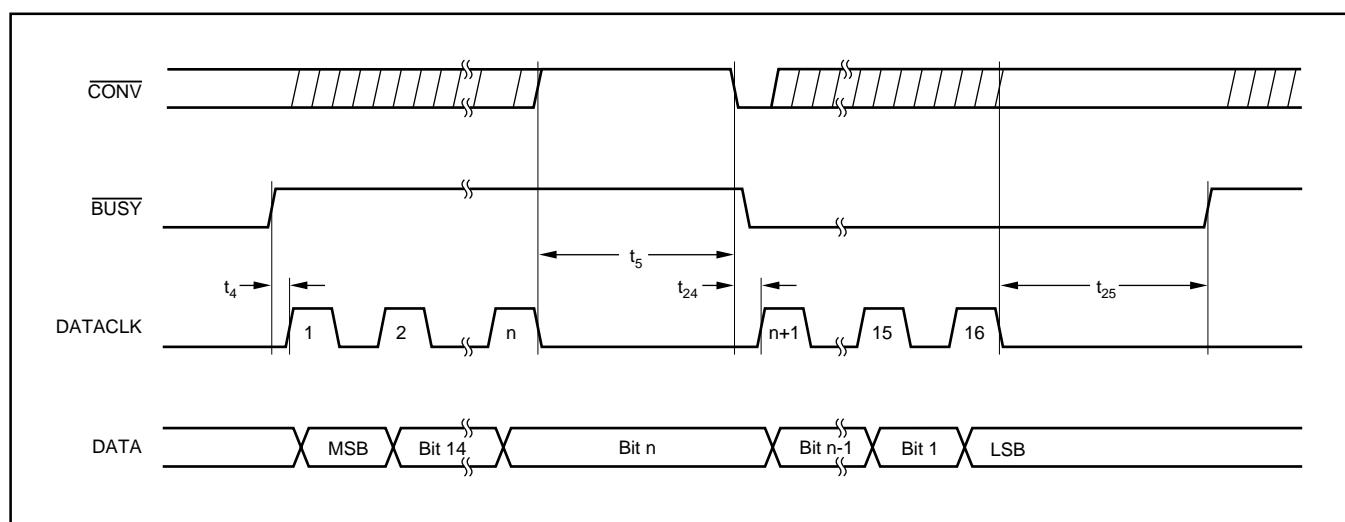


FIGURE 8. Serial Data Timing, External Clock, Clocking After the Conversion Completes and During the Next Conversion (EXT/INT HIGH, \overline{CS} LOW).

External DATACLK Active After the Conversion and During the Next Conversion

Figure 8 shows a method that is a hybrid of the two previous approaches. This method works very well for microcontrollers that do serial transfers 8 bits at a time and for slower microcontrollers. For example, if the fastest serial clock that the microcontroller can produce is 1 μ s, the approach shown in Figure 6 would result in a diminished throughput (26kHz maximum conversion rate). The method described in Figure 7 could not be used without risk of affecting the conversion result (the clock would have to be active after time t_2). The approach in Figure 8 results in an improved throughput rate (33kHz maximum with a 1 μ s clock) and DATACLK is not active after time t_2 .

COMPATIBILITY WITH THE ADS7812

The only difference between the ADS7812 and the ADS7813 is in the internal control logic and the digital interface. Since the ADS7812 is a 12-bit converter, the internal shift register is 12 bits wide. In addition, only 12-bit decisions are made during the conversion. Thus, the ADS7812's conversion time is approximately 75% of the ADS7813's.

In the internal DATACLK mode, the ADS7812 produces 12 DATACLK periods during the conversion instead of the ADS7813's 16 (see Figure 5). In the external DATACLK mode, the ADS7812 can accept 16 clock periods on DATACLK. At the start of the 13th clock cycle, the DATA output will go LOW and remain LOW. Thus, Figures 6, 7, 8, and the associated times in Table II can also be used for the ADS7812, but the last four bits of the conversion result will be zero.

CHIP SELECT (CS)

The CS input allows the digital outputs of the ADS7813 to be disabled and gates the external DATACLK signal when EXT/INT is HIGH. See Figure 9 for the enable and disable time associated with CS and Figure 3 for a block diagram of the ADS7813's logic. The digital outputs can be disabled at any time.

Note that a conversion is initiated on the falling edge of CONV even if CS is HIGH. If the EXT/INT input is LOW (internal DATACLK) and CS is HIGH during the entire conversion, the previous conversion result will be lost (the serial transmission occurs but DATA and DATACLK are disabled).

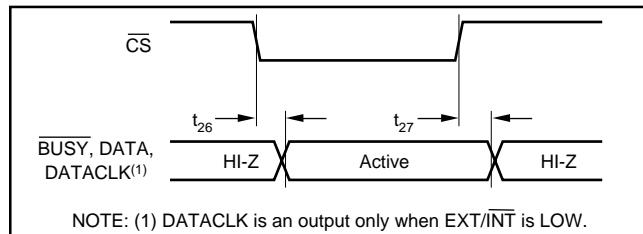


FIGURE 9. Enable and Disable Timing for Digital Outputs.

ANALOG INPUT

The ADS7813 offers a number of input ranges. This is accomplished by connecting the three input resistors to either the analog input (V_{IN}), to ground (GND), or to the 2.5V reference buffer output (BUF). Table I shows the input ranges that are typically used in most data acquisition applications. These ranges are all specified to meet the specifications given in the Specifications table. Table IV contains a complete list of ideal input ranges, associated input connections, and comments regarding the range.

ANALOG INPUT RANGE (V)	CONNECT R1 _{IN} TO	CONNECT R2 _{IN} TO	CONNECT R3 _{IN} TO	INPUT IMPEDANCE (k Ω)	COMMENT
0.3125 to 2.8125	V_{IN}	V_{IN}	V_{IN}	> 10,000	Specified offset and gain
-0.417 to 2.916	V_{IN}	V_{IN}	BUF	26.7	V_{IN} cannot go below GND - 0.3V
0.417 to 3.750	V_{IN}	V_{IN}	GND	26.7	Offset and gain not specified
± 3.333	V_{IN}	BUF	V_{IN}	21.3	Specified offset and gain
-15 to 5	V_{IN}	BUF	BUF	45.7	Offset and gain not specified
± 10	V_{IN}	BUF	GND	45.7	Specified offset and gain
0.833 to 7.5	V_{IN}	GND	V_{IN}	21.3	Offset and gain not specified
-2.5 to 17.5	V_{IN}	GND	BUF	45.7	Exceeds absolute maximum V_{IN}
2.5 to 22.5	V_{IN}	GND	GND	45.7	Exceeds absolute maximum V_{IN}
0 to 2.857	BUF	V_{IN}	V_{IN}	45.7	Offset and gain not specified
-1 to 3	BUF	V_{IN}	BUF	21.3	V_{IN} cannot go below GND - 0.3V
0 to 4	BUF	V_{IN}	GND	21.3	Specified offset and gain
-6.25 to 3.75	BUF	BUF	V_{IN}	26.7	Offset and gain not specified
0 to 10	BUF	GND	V_{IN}	26.7	Specified offset and gain
0.357 to 3.214	GND	V_{IN}	V_{IN}	45.7	Offset and gain not specified
-0.5 to 3.5	GND	V_{IN}	BUF	21.3	V_{IN} cannot go below GND - 0.3V
0.5 to 4.5	GND	V_{IN}	GND	21.3	Specified offset and gain
± 5	GND	BUF	V_{IN}	26.7	Specified offset and gain
1.25 to 11.25	GND	GND	V_{IN}	26.7	Offset and gain not specified

TABLE IV. Complete List of Ideal Input Ranges.

The input impedance results from the various connections and the internal resistor values (refer to the block diagram on the front page of this data sheet). The internal resistor values are typical and can change by $\pm 30\%$, due to process variations. However, the ratio matching of the resistors is considerably better than this. Thus, the input range will vary only a few tenths of a percent from part to part, while the input impedance can vary up to $\pm 30\%$.

The Specifications table contains the maximum limits for the variation of the analog input range, but only for those ranges where the comment field shows that the offset and gain are specified (this includes all the ranges listed in Table I). For the other ranges, the offset and gain are not tested and are not specified.

Five of the input ranges in Table IV are not recommended for general use. The upper-end of the -2.5V to $+17.5\text{V}$ range and $+2.5\text{V}$ to $+22.5\text{V}$ range exceed the absolute maximum analog input voltage. These ranges can still be used as long as the input voltage remains under the absolute maximum, but this will moderately to significantly reduce the full-scale range of the converter.

Likewise, three of the input ranges involve the connection at $R_{2\text{IN}}$ being driven below GND. This input has a reverse-biased ESD protection diode connection to ground. If $R_{2\text{IN}}$ is taken below GND $- 0.3\text{V}$, this diode will be forward-biased and will clamp the negative input at -0.4V to -0.7V , depending on the temperature. Since the negative full-scale value of these input ranges exceed -0.4V , they are not recommended.

Note that Table IV assumes that the voltage at the REF pin is $+2.5\text{V}$. This is true if the internal reference is being used or if the external reference is $+2.5\text{V}$. Other reference voltages will change the values in Table IV.

HIGH IMPEDANCE MODE

When $R_{1\text{IN}}$, $R_{2\text{IN}}$, and $R_{3\text{IN}}$ are connected to the analog input, the input range of the ADS7813 is 0.3125V to 2.8125V and the input impedance is greater than $10\text{M}\Omega$. This input range can be used to connect the ADS7813 directly to a wide variety of sensors. Figure 10 shows the impedance of the sensor versus the change in ILE and DLE of the ADS7813. The performance of the ADS7813 can be improved for higher sensor impedance by allowing more time for acquisition. For example, $10\mu\text{s}$ of acquisition time will approximately double sensor impedance for the same ILE/DLE performance.

The input impedance and capacitance of the ADS7813 are very stable with temperature. Assuming that this is true of the sensor as well, the graph shown in Figure 10 will vary less than a few percent over the ensured temperature range of the ADS7813. If the sensor impedance varies significantly with temperature, the worst-case impedance should be used.

DRIVING THE ADS7813 ANALOG INPUT

In general, any *reasonably fast*, high-quality operational or instrumentation amplifier can be used to drive the ADS7813 input. When the converter enters the acquisition mode, there is some charge injection from the converter input to the amplifier output. This can result in inadequate settling time

with slower amplifiers. Be very careful with single-supply amplifiers, particularly if their output will be required to swing very close to the supply rails.

In addition, be careful in regards to the amplifier linearity. The outputs of single-supply and rail-to-rail amplifiers can saturate as they approach the supply rails. Rather than the amplifier transfer function being a straight line, the curve can become severely 'S' shaped. Also, watch for the point where the amplifier switches from sourcing current to sinking current. For some amplifiers, the transfer function can be noticeably discontinuous at this point, causing a significant change in the output voltage for a much smaller change on the input.

Texas Instruments manufactures a wide variety of operational and instrumentation amplifiers that can be used to drive the input of the ADS7813. These include the OPA627, OPA132, and INA110.

REFERENCE

The ADS7813 can be operated with its internal 2.5V reference or an external reference. By applying an external reference voltage to the REF pin, the internal reference voltage is overdriven. The voltage at the REF input is internally buffered by a unity gain buffer. The output of this buffer is present at the BUF and CAP pins.

REF

The REF pin is the output of the internal 2.5V reference or the input for an external reference. A $1\mu\text{F}$ to $2.2\mu\text{F}$ tantalum capacitor should be connected between this pin and ground. The capacitor should be placed as close to the ADS7813 as possible.

When using the internal reference, the REF pin should not be connected to any type of significant load. An external load will cause a voltage drop across the internal $4\text{k}\Omega$ resistor that is in series with the internal reference. Even a $40\text{M}\Omega$ external load to ground will cause a decrease in the full-scale range of the converter by 6 LSBs.

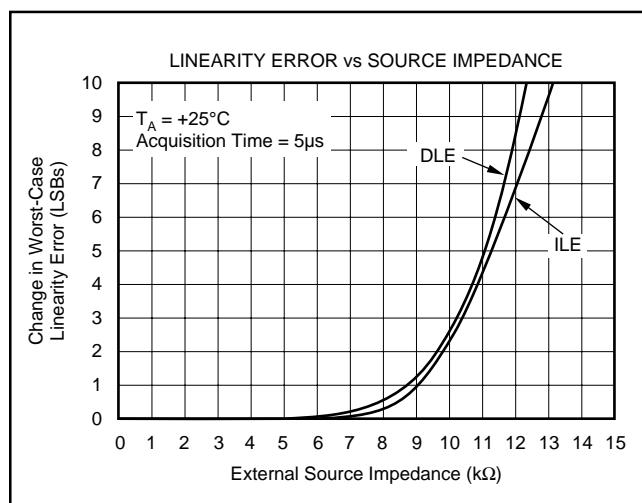


FIGURE 10. Linearity Error vs Source Impedance in the High Impedance Mode ($R_{1\text{IN}} = R_{2\text{IN}} = R_{3\text{IN}} = V_{\text{IN}}$).

The range for the external reference is 2.3V to 2.7V. The voltage on REF determines the full-scale range of the converter and the corresponding LSB size. Increasing the reference voltage will increase the LSB size in relation to the internal noise sources which, in turn, can improve signal-to-noise ratio. Likewise, decreasing the reference voltage will reduce the LSB size and signal-to-noise ratio.

CAP

The CAP pin is used to compensate the internal reference buffer. A 1 μ F tantalum capacitor in parallel with a 0.01 μ F ceramic capacitor should be connected between this pin and ground, with the ceramic capacitor placed as close to the ADS7813 as possible. The total value of the capacitance on the CAP pin is critical to optimum performance of the ADS7813. A value larger than 2.0 μ F could overcompensate the buffer while a value lower than 0.5 μ F may not provide adequate compensation. The ESR (equivalent series resistance) of these compensation capacitors is also critical. Keep the total ESR under 3 Ω . See the Typical Characteristic curve, */Worst-Case INL/ vs ESR of Reference Buffer Compensation Capacitor*, for how the worst-case INL is affected by ESR.

BUF

The voltage on the BUF pin is the output of the internal reference buffer. This pin is used to provide +2.5V to the analog input or inputs for the various input configurations.

The BUF output can provide up to 1mA of current to an external load. The load should be constant as a variable load could affect the conversion result by modulating the BUF voltage. Also note that the BUF output will show significant glitches as each bit decision is made during a conversion. Between conversions, the BUF output is quiet.

POWER DOWN

The ADS7813 has a power-down mode that is activated by taking CONV LOW and then PWRD HIGH. This will power down all of the analog circuitry including the reference, reducing power dissipation to under 50 μ W. To exit the

power-down mode, CONV is taken HIGH and then PWRD is taken LOW. Note that a conversion will be initiated if PWRD is taken HIGH while CONV is LOW.

While in the power-down mode, the voltage on the capacitors connected to CAP and REF will begin to leak off. The voltage on the CAP capacitor leaks off much more rapidly than on the REF capacitor (the REF input of the ADS7813 becomes high-impedance when PWRD is HIGH—this is not true for the CAP input). When the power-down mode is exited, these capacitors must be allowed to recharge and settle to a 16-bit level. Figure 11 shows the amount of time typically required to obtain a valid 16-bit result based on the amount of time spent in power down (at room temperature). This figure assumes that the total capacitance on the CAP pin is 1.0 μ F.

Figure 12 provides a circuit which can significantly reduce the power up time if the power down time will be fairly brief (a few seconds or less). A low on-resistance MOSFET is used to disconnect the capacitance on the CAP pin from the leakage paths internal to the ADS7813. This allows the capacitors to retain their charge for a much longer period of time, reducing the time required to recharge them at power up. With this circuit, the power-down time can be extended to tens or hundreds of milliseconds with almost instantaneous power up.

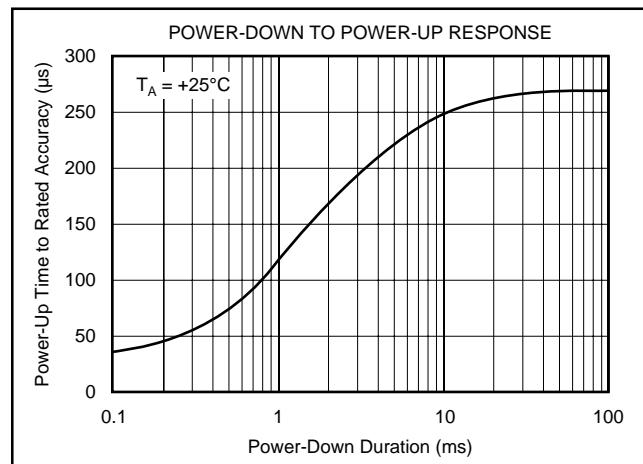


FIGURE 11. Power-Down to Power-Up Response.

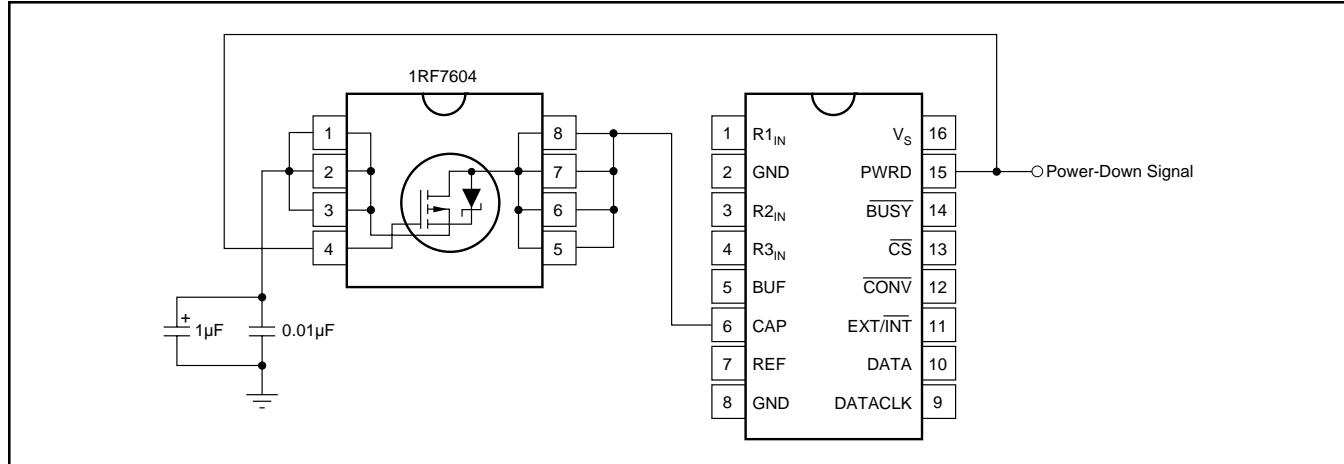


FIGURE 12. Improved Power-Up Response Circuit.

LAYOUT

The ADS7813 should be treated as a precision analog component and should reside completely on the analog portion of the printed circuit board. Ideally, a ground plane should extend underneath the ADS7813 and under all other analog components. This plane should be separate from the digital ground until they are joined at the power supply connection. This will help prevent dynamic digital ground currents from modulating the analog ground through a common impedance to power ground.

The +5V power should be clean, well-regulated, and separate from the +5V power for the digital portion of the design. One possibility is to derive the +5V supply from a linear regulator located near the ADS7813. If derived from the digital +5V power, a 5Ω to 10Ω resistor should be placed in series with the power connection from the digital supply. It may also be necessary to increase the bypass capacitance near the V_S pin (an additional $100\mu F$ or greater capacitor in parallel with the $10\mu F$ and $0.1\mu F$ capacitors). For designs with a large number of digital components or very high speed digital logic, this simple power supply filtering scheme may not be adequate.

SENSITIVITY TO EXTERNAL DIGITAL SIGNALS

All successive approximation register-based A/D converters are sensitive to external sources of noise. The reason for this will be explained in the following paragraphs. For the ADS7813 and similar A/D converters, this noise most often originates due to the transition of external digital signals. While digital signals that run near the converter can be the source of the noise, the biggest problem occurs with the digital inputs to the converter itself.

In many cases, the system designer may not be aware that there is a problem or a potential for a problem. For a 12-bit system, these problems typically occur at the least significant bits and only at certain places in the converter's transfer function. For a 16-bit converter, the problem can be much easier to spot.

For example, the timing diagram in Figure 2 shows that the CONV signal should return HIGH sometime during time t_2 . In fact, the CONV signal can return HIGH at any time during the conversion. However, after time t_2 , the transition of the CONV signal has the potential of creating a good deal of noise on the ADS7813 die. If this transition occurs at just precisely the wrong time, the conversion results could be affected. In a similar manner, transitions on the DATACLK input could affect the conversion result.

For the ADS7813, there are 16 separate bit decisions which are made during the conversion. The most significant bit decision is made first, proceeding to the least significant bit at the end of the conversion. Each bit decision involves the assumption that the bit being tested should be set. This is combined with the result that has been achieved so far. The converter compares this combined result with the actual input voltage. If the combined result is too high, the bit is cleared. If the result is equal to or lower than the actual input voltage, the bit remains HIGH. This is why the basic architecture is referred to as *successive approximation register* (SAR).

If the result so far is getting very close to the actual input voltage, then the comparison involves two voltages which are very close together. The ADS7813 has been designed so that the internal noise sources are at a minimum just prior to the comparator result being latched. However, if an external digital signal transitions at this time, a great deal of noise will be coupled into the sensitive analog section of the ADS7813. Even if this noise produces a difference between the two voltages of only 2mV, the conversion result will be off by 52 counts or least significant bits (LSBs). (The internal LSB size of the ADS7813 is $38\mu V$ regardless of the input range.)

Once a digital transition has caused the comparator to make a wrong bit decision, the decision cannot be corrected (unless some type of error correction is employed). All subsequent bit decisions will then be wrong. Figure 13 shows a successive approximation process that has gone wrong. The dashed line represents what the correct bit decisions should have been. The solid line represents the actual result of the conversion.

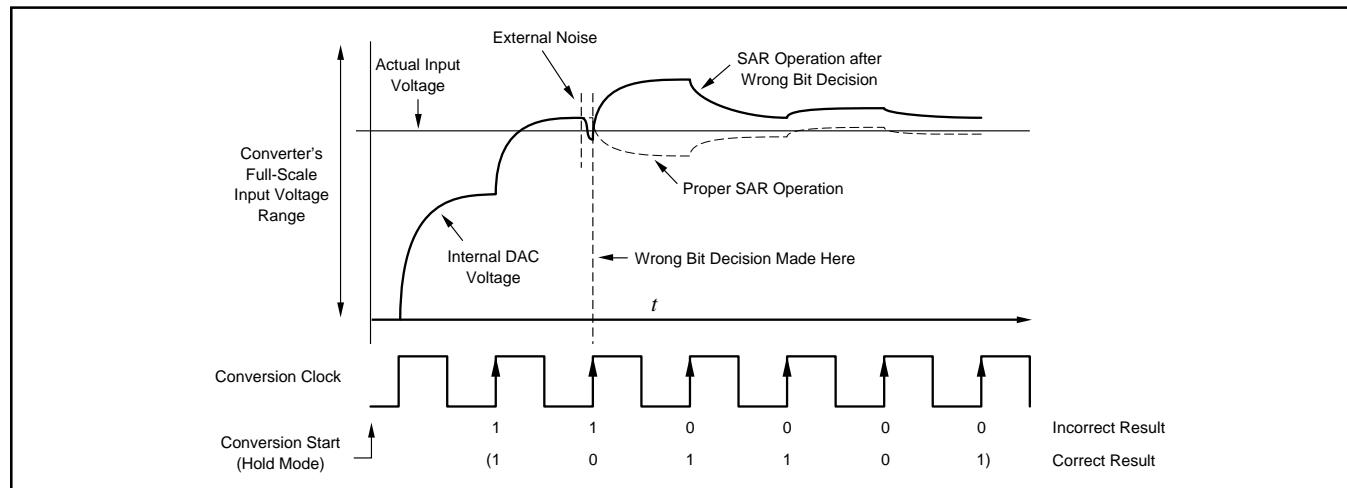


FIGURE 13. SAR Operation When External Noise Affects the Conversion.

Keep in mind that the time period when the comparator is most sensitive to noise is fairly small. Also, the peak portion of the noise event produced by a digital transition is fairly brief, as most digital signals transition in a few nanoseconds. The subsequent noise may last for a period of time longer than this and may induce further effects which require a longer settling time. However, in general, the event is over within a few tens of nanoseconds.

For the ADS7813, error correction is done when the tenth bit is decided. During this bit decision, it is possible to correct limited errors that may have occurred during previous bit decisions. However, after the tenth bit, no such correction is possible. Note that for the timing diagrams shown in Figures 2, 5, 6, 7, and 8, all external digital signals should remain static from 8 μ s after the start of a conversion until **BUSY** rises. The tenth bit is decided approximately 10 μ s to 11 μ s into the conversion.

APPLICATIONS INFORMATION

TRANSITION NOISE

If a low-noise DC input is applied to the ADS7813 and 1,000 conversions are performed, the digital output of the converter will vary slightly in output codes. This is true for all 16-bit SAR converters. The Transition Noise specification found in the *Electrical Characteristics* section is a statistical figure that represents the 1 sigma (σ) limit of these output codes.

Using a histogram to plot the number of occurrences of each output code, the distribution should appear bell-shaped with the peak of the curve representing the nominal output code for the given input voltage. The $\pm 1\sigma$, $\pm 2\sigma$, and $\pm 3\sigma$ limits around this nominal code should contain 68.3%, 95.5%, and 99.7%, respectively, of the conversion results. As a rough approximation, multiplying transition noise by 6 ($\pm 3\sigma$) will yield the number of unique output codes which should be present in 1,000 conversions.

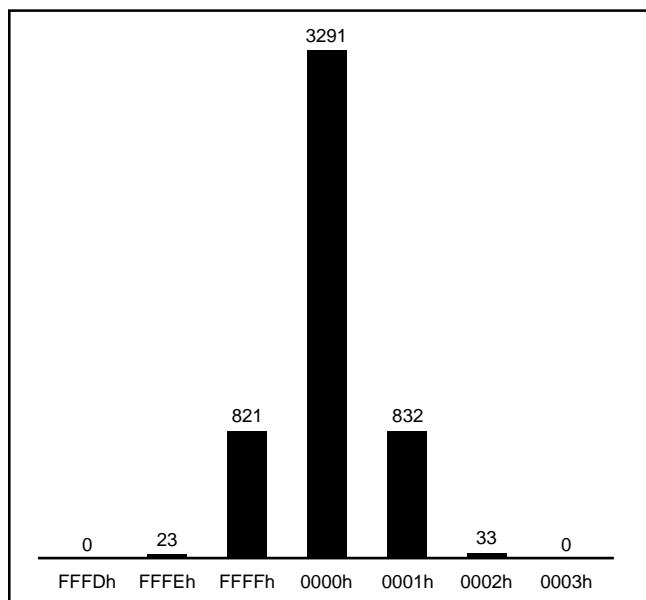


FIGURE 14. Histogram of 5,000 Conversions with Input Grounded.

The ADS7813 has a transition noise figure of 0.6LSB, yielding approximately 4 different output codes for 1,000 conversions. However, since $\pm 3\sigma$ is only 99.7%, up to three conversions have some chance of being outside this range. In addition, the differential linearity error of each code and the quantization performed by the converter result in histograms which can deviate from the ideal. Figure 14 shows a histogram of 5,000 conversions from the ADS7813.

AVERAGING

The noise of the converter can be reduced by averaging conversion results. The noise will be reduced by a factor of $1/\sqrt{n}$, where n is the number of averages. For example, averaging four conversions will reduce transition noise by half, to 0.3LSBs. Averaging should only be used for low-frequency signals.

For higher frequency signals, a digital filter can be used to reduce noise. This works in a similar manner to averaging: for every reduction in the signal bandwidth by two, the signal-to-noise ratio will improve by 3dB.

QSPI INTERFACING

Figure 15 shows a simple interface between the ADS7813 and any queued serial peripheral interface (QSPI) equipped microcontroller (available on several Motorola devices). This interface assumes that the convert pulse does not originate from the microcontroller and that the ADS7813 is the only serial peripheral.

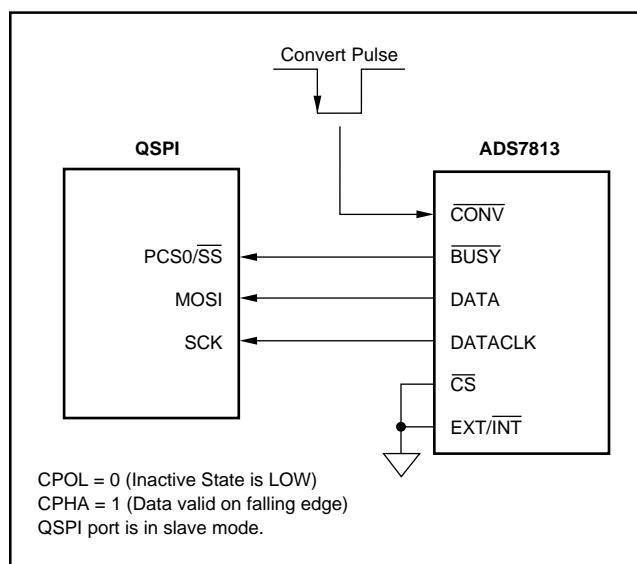


FIGURE 15. QSPI Interface to the ADS7813.

Before enabling the QSPI interface, the microcontroller must be configured to monitor the slave select (\bar{SS}) line. When a LOW to HIGH transition occurs (indicating the end of a conversion), the port can be enabled. If this is not done, the microcontroller and A/D converter may not be properly synchronized. (The slave select line simply enables communication—it does not indicate the start or end of a serial transfer.)

Figure 16 shows a QSPI-equipped microcontroller interfacing to three ADS7813s. There are many possible variations to this interface scheme. As shown, the QSPI port produces a common $\overline{\text{CONV}}$ signal which initiates a conversion on all three converters. After the conversions are finished, each result is transferred in turn. The QSPI port is completely programmable to handle the timing and transfers without processor intervention. If the $\overline{\text{CONV}}$ signal is generated in this way, it should be possible to make both AC and DC measurements with the ADS7813, as the $\overline{\text{CONV}}$ signal will have low jitter. Note that if the $\overline{\text{CONV}}$ signal is generated via software commands, it will have a good deal of jitter and only low frequency (DC) measurements can be made.

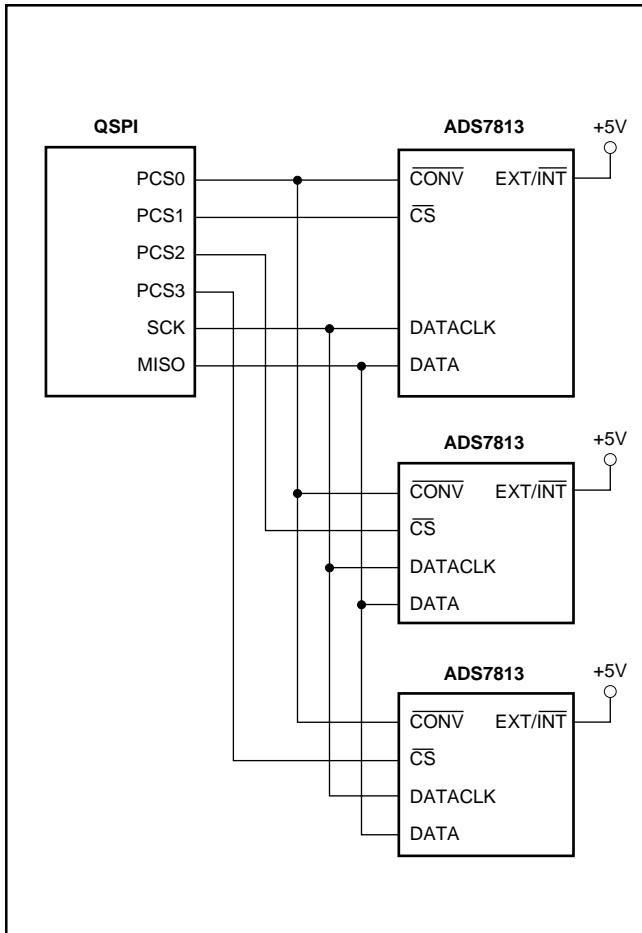


FIGURE 16. QSPI Interface to Three ADS7813s.

SPI INTERFACING

The serial peripheral interface (SPI) is directly related to the QSPI and both Figures 15 and 16 can be used as a guide for connecting the ADS7813 to SPI-equipped microcontrollers. For most microcontrollers, the SPI port is capable of 8-bit transfers only. In the case of Figure 15, be aware that the microcontroller may have to be capable of fetching the 8 most significant bits before they are overwritten by the 8 least significant bits.

DSP56002 INTERFACING

The DSP56002 serial interface has an SPI compatibility mode with some enhancements. Figure 17 shows an interface between the ADS7813 and the DSP56002. As with the QSPI interface of Figure 15, the DSP56002 must be programmed to enable the serial interface when a LOW to HIGH transition on SCI occurs.

The DSP56002 can also provide the $\overline{\text{CONV}}$ signal, as shown in Figure 18. The receive and transmit sections of the interface are decoupled (asynchronous mode) and the transmit section is set to generate a word length frame sync every other transmit frame (frame rate divider set to 2). The prescale modulus should be set to produce a transmit frame at twice the desired conversion rate.

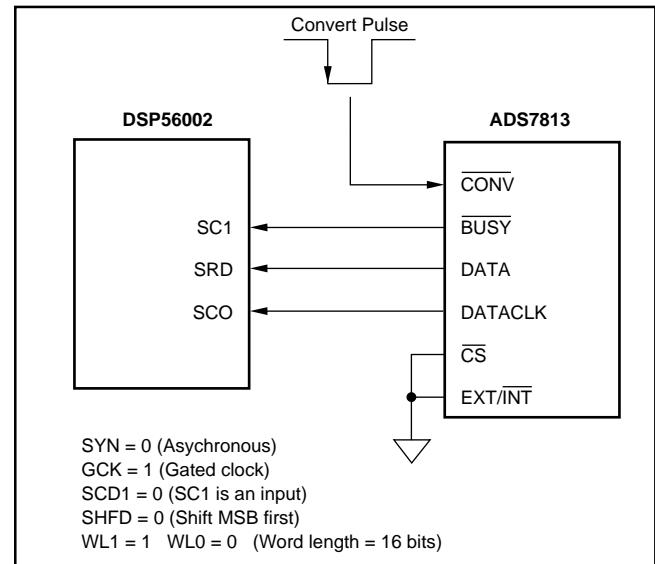


FIGURE 17. DSP56002 Interface to the ADS7813.

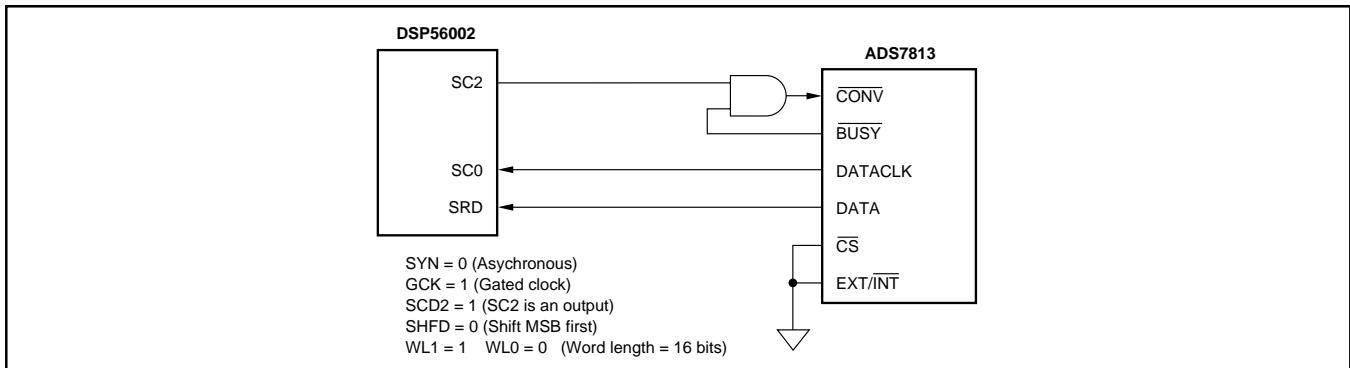


FIGURE 18. DSP56002 Interface to the ADS7813. Processor Initiates Conversions.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ADS7813U	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	ADS7813U	Samples
ADS7813U/1K	ACTIVE	SOIC	DW	16	1000	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	ADS7813U	Samples
ADS7813UB	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	ADS7813U B	Samples
ADS7813UE4	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	ADS7813U	Samples
ADS7813UG4	ACTIVE	SOIC	DW	16	40	RoHS & Green	NIPDAU-DCC	Level-3-260C-168 HR	-40 to 85	ADS7813U	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

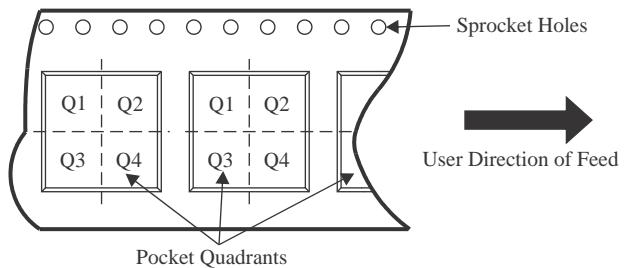
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

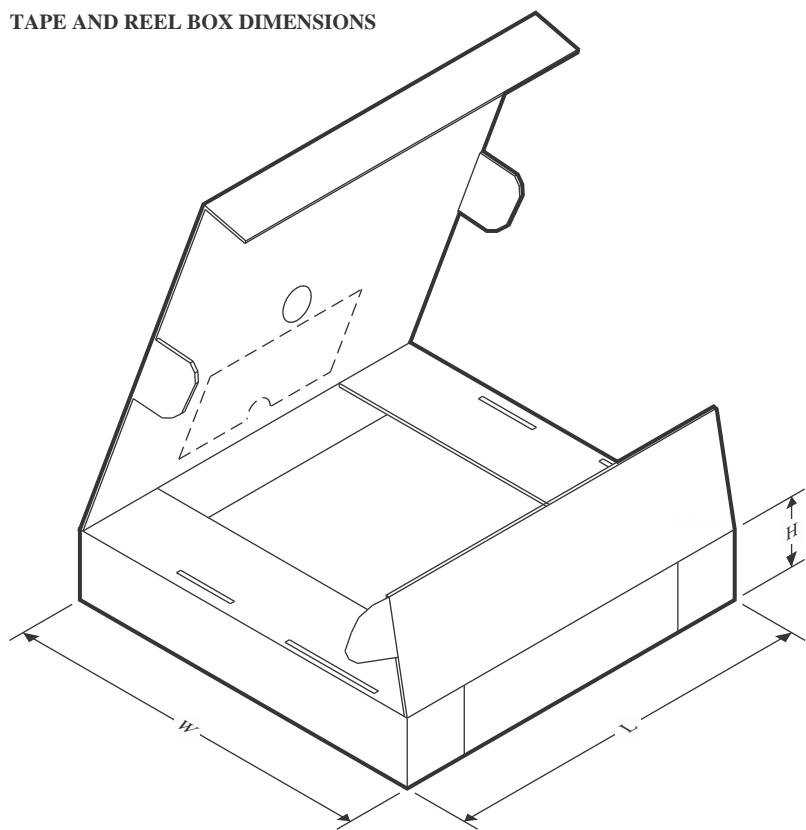
TAPE AND REEL INFORMATION


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ADS7813U/1K	SOIC	DW	16	1000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADS7813U/1K	SOIC	DW	16	1000	350.0	350.0	43.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μ m)	B (mm)
ADS7813U	DW	SOIC	16	40	506.98	12.7	4826	6.6
ADS7813UB	DW	SOIC	16	40	506.98	12.7	4826	6.6
ADS7813UE4	DW	SOIC	16	40	506.98	12.7	4826	6.6
ADS7813UG4	DW	SOIC	16	40	506.98	12.7	4826	6.6

GENERIC PACKAGE VIEW

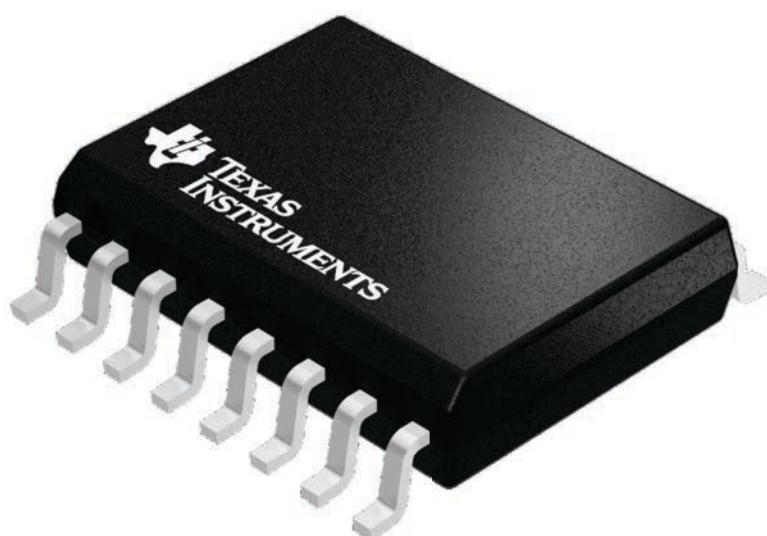
DW 16

SOIC - 2.65 mm max height

7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4224780/A

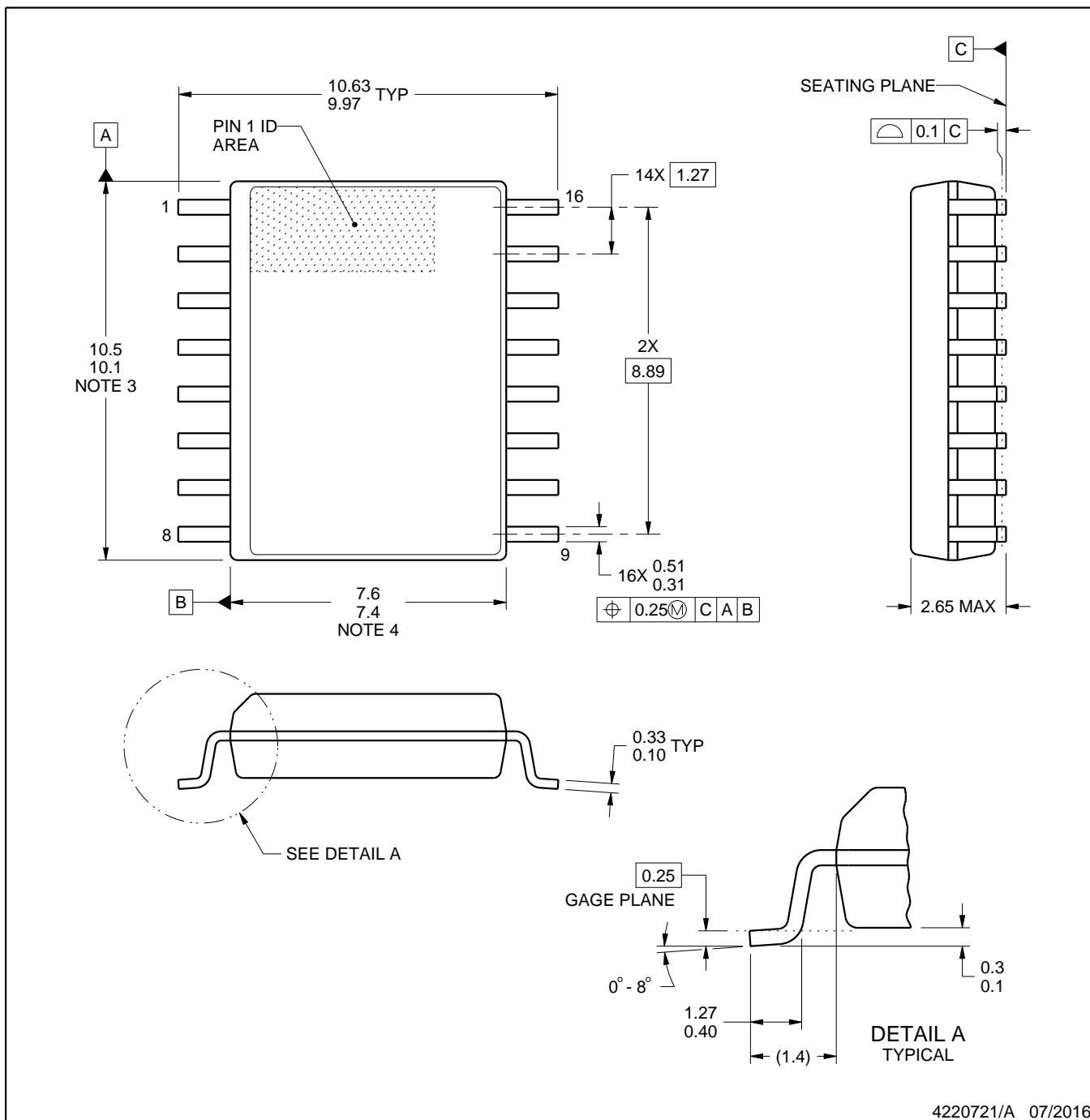


PACKAGE OUTLINE

DW0016A

SOIC - 2.65 mm max height

SOIC



4220721/A 07/2016

NOTES:

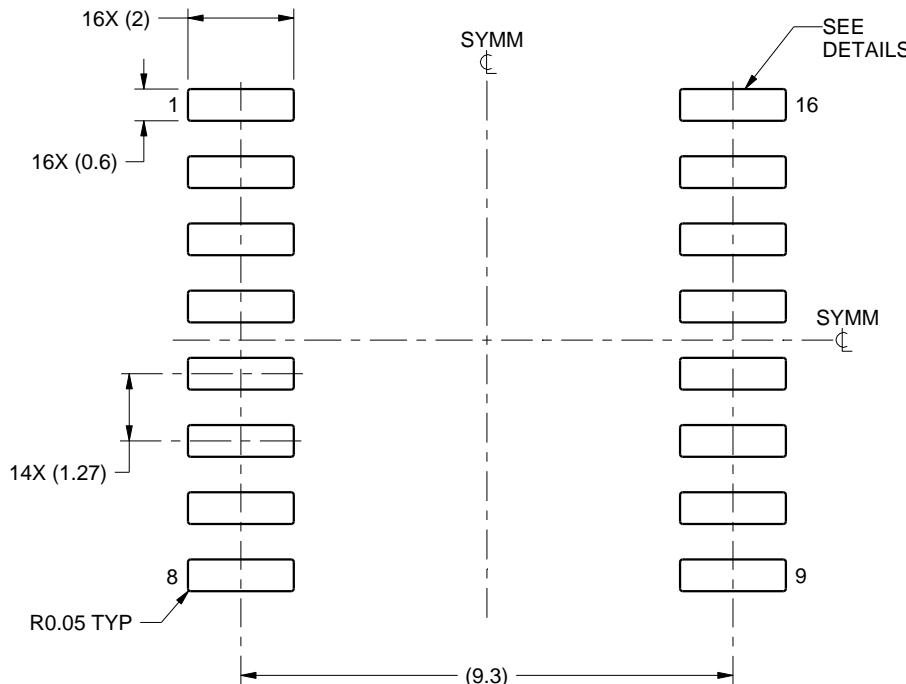
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

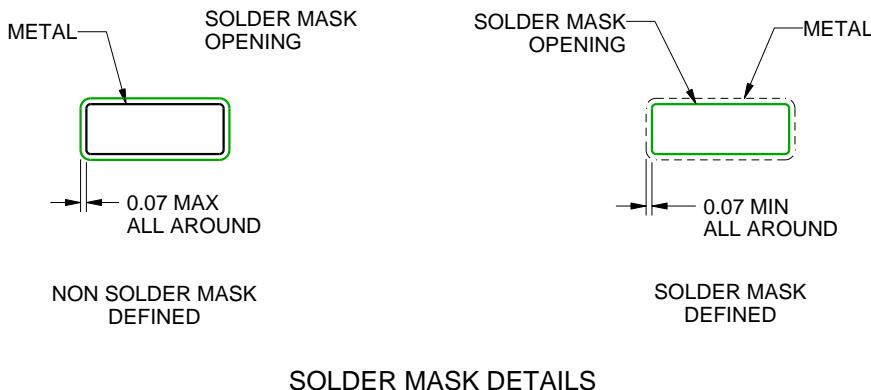
DW0016A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:7X



4220721/A 07/2016

NOTES: (continued)

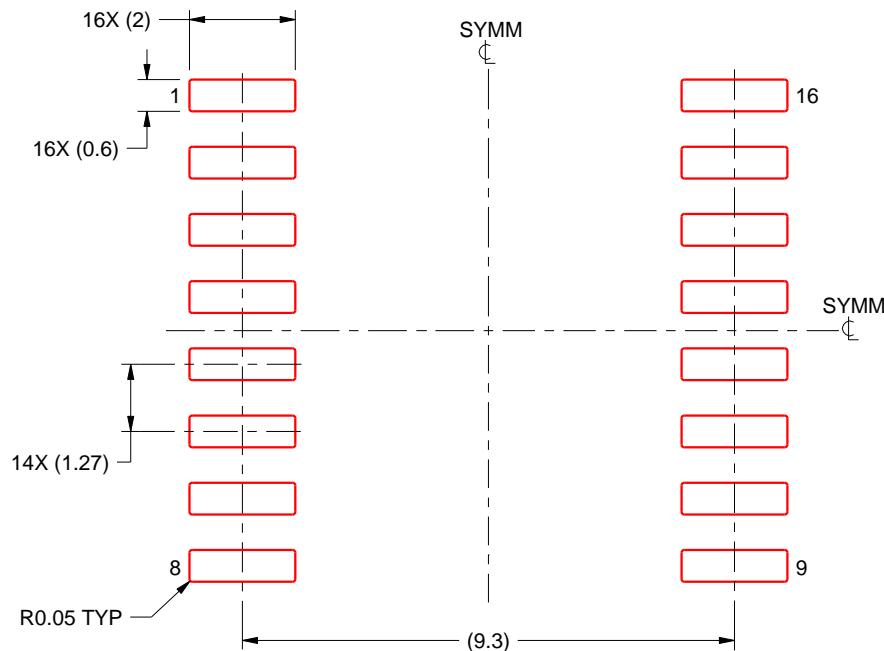
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0016A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220721/A 07/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2024, Texas Instruments Incorporated